BLF884P; BLF884PS UHF power LDMOS transistor Rev. 3 – 1 September 2015

Product profile 1.

1.1 General description

A 350 W LDMOS RF power transistor for broadcast transmitter applications and industrial applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications.

Table 1. **Application information**

RF performance at $V_{DS} = 50$ V unless otherwise specified.

Mode of operation	f	$P_{L(AV)}$	P _{L(M)}	Gp	η_D	IMD3	IMD _{shldr}	PAR
	(MHz)	(W)	(W)	(dB)	(%)	(dBc)	(dBc)	(dB)
RF performance in a common source 860 MHz narrowband test circuit								
2-tone, class-AB	f ₁ = 860; f ₂ = 860.1	150	-	21	46	-32	-	-
DVB-T (8k OFDM)	858	70	-	21	33	-	-31 <mark>11</mark>	8.2 [2]
RF performance in a common source 470 MHz to 860 MHz broadband test circuit								
DVB-T (8k OFDM)	858	70	-	20	32	-	-32 <mark>[1]</mark>	8.0 [2]

[1] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

[2] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

- Excellent ruggedness
- Optimum thermal behavior and reliability, R_{th(i-c)} = 0.22 K/W
- High power gain
- High efficiency
- Designed for broadband operation (470 MHz to 860 MHz)
- Internal input matching for high gain and optimum broadband operation
- Excellent reliability
- Easy power control
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

1.3 Applications

- Communication transmitter applications in the UHF band
- Industrial applications in the UHF band

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
BLF884P	(SOT1121A)		
1	drain1		
2	drain2		
3	gate1		3
4	gate2		5
5	source		4 1 2 sym117
BLF884P	S (SOT1121B)		<i></i>
1	drain1		1
<u> </u>			



[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLF884P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A			
BLF884PS	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage		-	104	V
V _{GS}	gate-source voltage		-0.5	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

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5. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 80 °C; $P_{L(AV)}$ = 70 W	0.22	K/W
	is measured under DE senditions			

[1] R_{th(j-c)} is measured under RF conditions.

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 1.2 mA	[1]	104	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 120 mA	[1]	1.4	1.9	2.4	V
I _{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V		-	-	1.4	μA
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$		-	19	-	A
I _{GSS}	gate leakage current	V_{GS} = 10 V; V_{DS} = 0 V		-	-	140	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 4.25 A$	<u>[1]</u>	-	240	-	mΩ
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	[2]	-	105	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz		-	34	-	pF
C _{rss}	reverse transfer capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz		-	0.7	-	pF

[1] I_D is the drain current.

[2] Capacitance values without internal matching.

Table 7.RF characteristics

RF characteristics in Ampleon production narrowband test circuit; $T_{case} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
2-Tone, c	ass-AB						
V _{DS}	drain-source voltage			-	50	-	V
I _{Dq}	quiescent drain current		[1]	-	0.65	-	А
$P_{L(AV)}$	average output power	f ₁ = 860 MHz; f ₂ = 860.1 MHz		150	-	-	W
G _p	power gain	f ₁ = 860 MHz; f ₂ = 860.1 MHz		20	21	-	dB
η_D	drain efficiency	f ₁ = 860 MHz; f ₂ = 860.1 MHz		42	46	-	%
IMD3	third-order intermodulation distortion	f ₁ = 860 MHz; f ₂ = 860.1 MHz		-	-32	-28	dBc

Table 7. RF characteristics ... continued

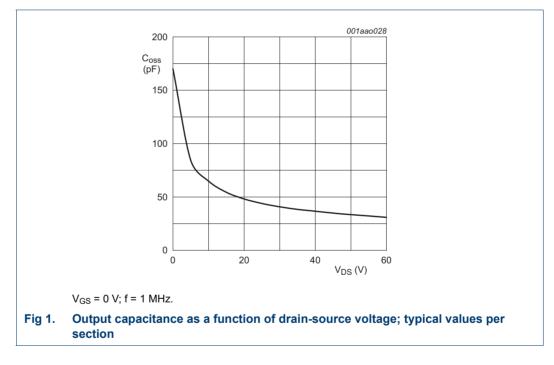
RF characteristics in Ampleon production narrowband test circuit; $T_{case} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
DVB-T (8	k OFDM), class-AB						
V _{DS}	drain-source voltage			-	50	-	V
I _{Dq}	quiescent drain current		[1]	-	0.65	-	А
P _{L(AV)}	average output power	f = 858 MHz		70	-	-	W
G _p	power gain	f = 858 MHz		20	21	-	dB
η_D	drain efficiency	f = 858 MHz		30	33	-	%
IMD _{shldr}	intermodulation distortion shoulder	f = 858 MHz	[2]	-	-31	-27	dBc
PAR	peak-to-average ratio	f = 858 MHz	[3]	-	8.2	-	dB

[1] I_{dq} for total device

[2] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

[3] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.



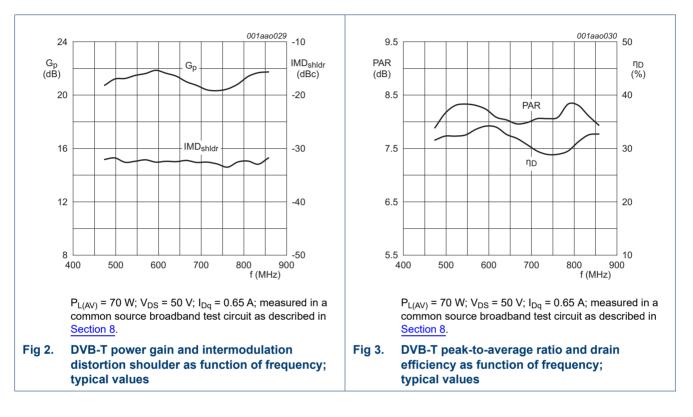
6.1 Ruggedness in class-AB operation

The BLF884P and BLF884PS are capable of withstanding a load mismatch corresponding to VSWR of \geq 40 : 1 through all phases under the following conditions: V_{DS} = 50 V; f = 860 MHz at rated power.

7. Application information

7.1 Broadband RF figures

7.1.1 DVB-T



7.2 Impedance information

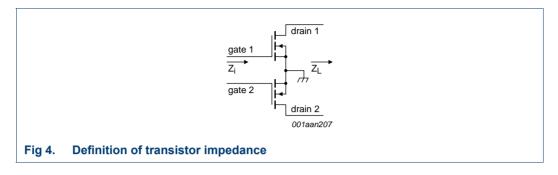


Table 8. Typical push-pull impedance

Simulated Z_i and Z_L	device impedance	; impedance info a	$t V_{DS} = 50 V$	and $P_{L(AV)} = 70 W (DVB-T)$).
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f	Zi	ZL
MHz	Ω	Ω
300	0.984 – j3.485	8.315 + j1.246
325	1.009 – j2.805	8.236 + j1.328
350	1.038 – j2.185	8.153 + j1.406
375	1.071 – j1.614	8.066 + j1.479
400	1.107 – j1.080	7.975 + j1.547
425	1.147 – j0.574	7.880 + j1.610
450	1.193 – j0.092	7.782 + j1.667
475	1.243 + j0.373	7.682 + j1.720
500	1.300 + j0.826	7.579 + j1.767
525	1.364 + j1.270	7.474 + j1.809
550	1.436 + j1.708	7.367 + j1.846
575	1.517 + j2.144	7.258 + j1.877
600	1.609 + j2.581	7.149 + j1.903
625	1.714 + j3.022	7.038 + j1.925
650	1.834 + j3.469	6.927 + j1.941
675	1.971 + j3.925	6.815 + j1.952
700	2.129 + j4.394	6.703 + j1.958
725	2.313 + j4.879	6.591 + j1.960
750	2.528 + j5.382	6.480 + j1.956
775	2.781 + j5.907	6.368 + j1.949
800	3.081 + j6.458	6.258 + j1.937
825	3.441 + j7.038	6.148 + j1.921
850	3.875 + j7.648	6.040 + j1.901
875	4.404 + j8.291	5.932 + j1.877
900	5.057 + j8.964	5.825 + j1.849
925	5.870 + j9.659	5.720 + j1.818
950	6.892 + j10.358	5.616 + j1.783
975	8.186 + j11.019	5.514 + j1.745
1000	9.829 + j11.566	5.413 + j1.704

8. Test information

Table 9.List of componentsFor test circuit, see Figure 5 and Figure 6.

Component	Description	Value		Remarks
B1, B2	semi rigid coax	25 Ω; 49.5 mm		UT-090C-25 (EZ 90-25)
C1, C2	multilayer ceramic chip capacitor	5.1 pF	<u>[1]</u>	
C3	multilayer ceramic chip capacitor	6.8 pF	<u>[1]</u>	
C4	multilayer ceramic chip capacitor	8.2 pF	<u>[1]</u>	
C10, C13, C14	multilayer ceramic chip capacitor	100 pF	[2]	
C11, C12	multilayer ceramic chip capacitor	10 pF	<u>[1]</u>	
C15, C16	multilayer ceramic chip capacitor	4.7 μF, 50 V		Kemet C1210X475K5RAC-TU or capacitor of same quality.
C17, C18, C23, C24	multilayer ceramic chip capacitor	100 pF	<u>[1]</u>	
C19, C20	multilayer ceramic chip capacitor	10 μF, 50 V		TDK C570X7R1H106KT000N or capacitor of same quality.
C21, C22	electrolytic capacitor	470 μF; 63 V		
C30	multilayer ceramic chip capacitor	13 pF	[3]	
C31	multilayer ceramic chip capacitor	2.2 pF	[3]	
C33, C34, C35	multilayer ceramic chip capacitor	100 pF	[3]	
C36, C37	multilayer ceramic chip capacitor	4.7 μF, 50 V		TDK C4532X7R1E475MT020U o capacitor of same quality.
L1	microstrip	-	[4]	(W \times L) 15 mm \times 13 mm
L2	microstrip	-	[4]	(W \times L) 5 mm \times 26 mm
L3, L32	microstrip	-	[4]	(W \times L) 2 mm \times 49.5 mm
L4	microstrip	-	[4]	(W \times L) 1.7 mm \times 3.5 mm
L5	microstrip	-	[4]	(W \times L) 2 mm \times 9.5 mm
L30	microstrip	-	[4]	(W \times L) 5 mm \times 13 mm
L31	microstrip	-	[4]	(W \times L) 2 mm \times 11 mm
L33	microstrip	-	[4]	(W \times L) 2 mm \times 3 mm
R1, R2	wire resistor	10 Ω		
R3, R4	SMD resistor	5.6 Ω		0805
R5, R6	wire resistor	100 Ω		
R7, R8	potentiometer	10 kΩ		

[1] American technical ceramics type 800B or capacitor of same quality.

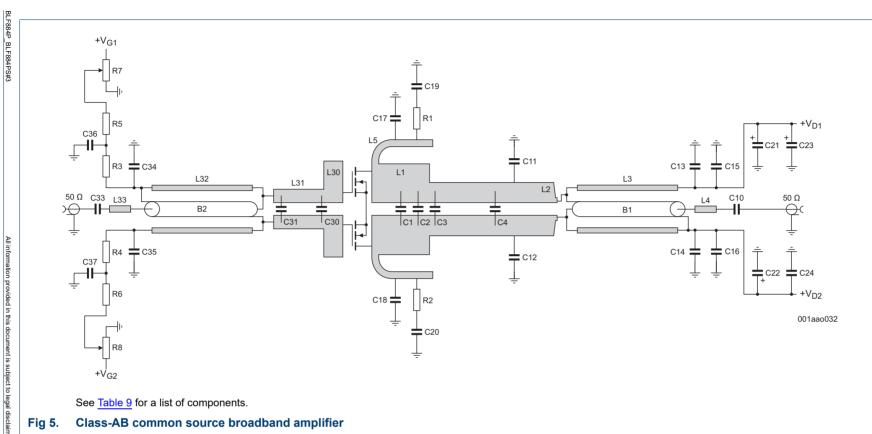
[2] American technical ceramics type 180R or capacitor of same quality.

[3] American technical ceramics type 100A or capacitor of same quality.

[4] Printed-Circuit Board (PCB): Taconic RF35; ϵ_r = 3.5 F/m; height = 0.762 mm; Cu (top/bottom metallization); thickness copper plating = 35 μ m.

Product data sheet





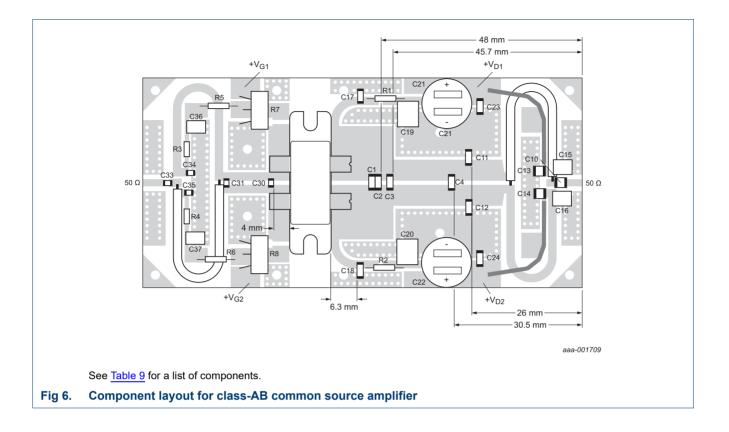
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9. Package outline

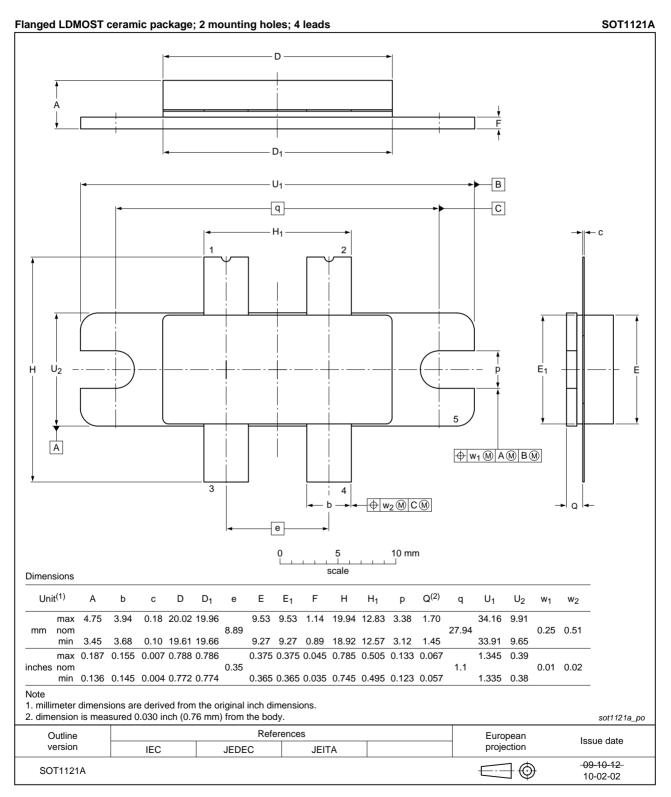


Fig 7. Package outline SOT1121A

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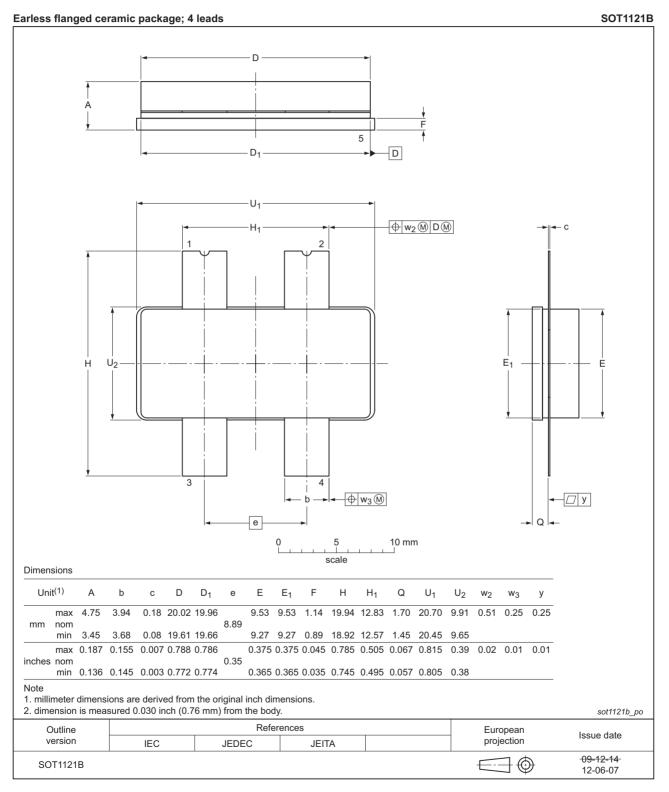


Fig 8. Package outline SOT1121B

BLF884P_BLF884PS#3

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CCDF	Complementary Cumulative Distribution Function
DVB	Digital Video Broadcast
DVB-T	Digital Video Broadcast - Terrestrial
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
OFDM	Orthogonal Frequency Division Multiplexing
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
UHF	Ultra High Frequency
VSWR	Voltage Standing-Wave Ratio

12. Revision history

Table 11.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF884P_BLF884PS#3	20150901	Product data sheet	-	BLF884P_BLF884PS v.2	
Modifications:	• The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.				
	 Legal texts have been adapted to the new company name where appropriate. 				
BLF884P_BLF884PS v.2	20111216	Product data sheet	-	BLF884P_BLF884PS v.1	
BLF884P_BLF884PS v.1	20111013	Objective data sheet	-	-	

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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